Preliminary

Renesas LSIs

M6MGD137W34DKT

134,217,728-BIT (8,388,608-WORD BY 16-BIT) CMOS FLASH MEMORY & 33,554,432-BIT (2,097,152-WORD BY 16-BIT) CMOS mobileRAM Stocked, rMCP (micro Multi Chip Backage)

Stacked- mMCP (micro Multi Chip Package)

DESCRIPTION

The M6MGD137W34DKT is a Stacked micro Multi Chip Package (S- μ MCP) that contents 128M-bit Flash memory and 32M-bit mobileRAM in a 52-pin TSOP for lead free use.

128M-bit Flash memory is a 8,388,608 words, single power supply and high performance non-volatile memory fabricated by CMOS technology for the peripheral circuit and DINOR IV (Divided bit-line NOR IV) architecture for the memory cell. All memory blocks are locked and can not be programmed or erased, when F-WP# is Low. Using Software Lock Release function, program or erase operation can be executed.

32M-bit mobileRAM is a 2,097,152 words high density RAM fabricated by CMOS technology for the peripheral circuit and DRAM cell for the memory array. The interface is compatible to an asynchronous SRAM.

The cells are automatically refreshed and the refresh control is not required for system. The device also has the partial block refresh scheme and the power down mode by writing the command.

The M6MGD137W34DKT is suitable for a high performance cellular phone and a mobile PC that are required to be small mounting area, weight and small power dissipation.

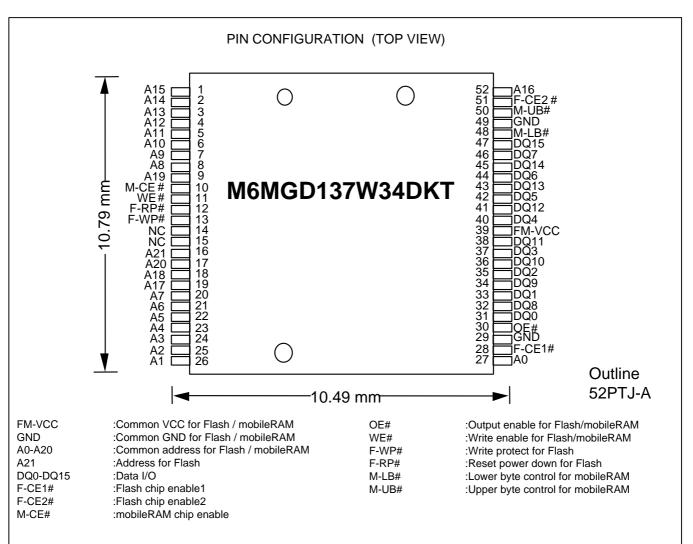
FEATURES

Access time Flash mobileRAM 70ns (Max.) 80ns (Max.)

Supply voltage Ambient temperature Package FM-VCC = 2.7 ~ 3.0V Ta=-40 ~ 85 °C 52pin TSOP(Type-II), Lead pitch 0.4mm Outer-lead finishing:Sn-Cu

APPLICATION

Mobile communication products





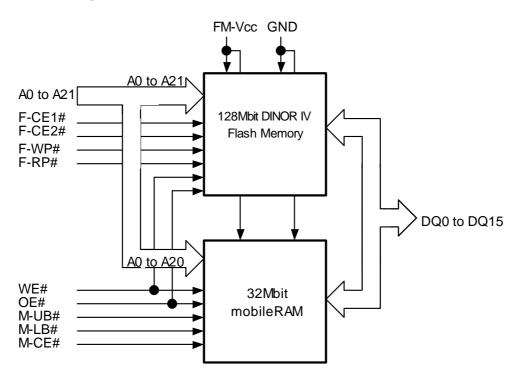
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Notice: This is not a final specification. Some parametric limits are subject to change.

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MCP Block Diagram



Note: In the 128M-bit DINOR(IV) Flash Memory lower 64Mbit is selected by F-CE1#="L" and upper 64Mbit is done by F-CE2#="L". Never select each chip at the same time. In the data sheet there are "VCC"s which mean "FM-VCC" (Common Vcc for Flash / mobileRAM).

In the Flash Memory part they mean A21, OE# and WE# are F-A21, F-OE# and F-WE#.

In the mobileRAM part UB# , LB#, OE# and WE# are M-UB# , M-LB#, M-OE# and M-WE#, respectively.

Capacitance

Symbol	Parameter		Conditions	Limits			Unit
				Min.	Тур.	Max.	Onic
CIN	Input capacitance	A21-A0, OE#, WE#, F-WP#, F-RP#, M- CE#, M-LB#, M-UB#, F-CE1#, F-CE2#	Ta=25°C, f=1MHz, Vin=Vout=0V			26	pF
							pF
							pF
							pF
COUT	Output Capacitance	DQ15-DQ0				34	pF



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RenesasTechnologyCorp.

Nippon Bldg.,6-2,Otemachi 2-chome,Chiyoda-ku,Tokyo,100-0004 Japan

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